NSN 5962-01-501-6907

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and monolithic and compatible cmos and erasable and programmable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Product Name:
Microcircuit, memory, digital, cmos, uv eraseable programmable logic array, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Time Rating Per Chacteristic:
30.00 nanoseconds af output megawatts
Memory Device Type:
Pal
Special Features:
Generic p/n v2500bql/lid shall be transparent tp permit ultraviolet light erasure
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
40 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0